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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/874,073	06/04/2001	Emir Gurer	8003-391	6810
21971 75	590 05/18/2004		EXAMINER	
	NSINI GOODRICH & R	KACKAR, RAM N		
	650 PAGE MILL ROAD PALO ALTO, CA 943041050		ART UNIT	PAPER NUMBER
			1763	
			DATE MAILED: 05/18/2004	1

Please find below and/or attached an Office communication concerning this application or proceeding.

		1
	Application No.	Applicant(s)
Office Action Comments	09/874,073	GURER ET AL.
Office Action Summary	Examiner	Art Unit
	Ram N Kackar	1763
The MAILING DATE of this communication apperent of the Period for Reply	ears on the cover sheet with th	e correspondence address
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply if NO period for reply is specified above, the maximum statutory period with Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be within the statutory minimum of thirty (30) ill apply and will expire SIX (6) MONTHS fr cause the application to become ABANDO	e timely filed  days will be considered timely.  om the mailing date of this communication.  NED (35 U.S.C. § 133).
Status		•
1) Responsive to communication(s) filed on 25 Ma     2a) This action is <b>FINAL</b> . 2b) This     3) Since this application is in condition for allowan closed in accordance with the practice under Ex	action is non-final. ce except for formal matters,	
Disposition of Claims		
4)	n from consideration.  /are rejected.	<b>.</b>
Application Papers		
9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) acce Applicant may not request that any objection to the d Replacement drawing sheet(s) including the correction 11) The oath or declaration is objected to by the Examiner	pted or b) objected to by the rawing(s) be held in abeyance. Son is required if the drawing(s) is	See 37 CFR 1.85(a). objected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign part a) All b) Some * c) None of:  1. Certified copies of the priority documents  2. Certified copies of the priority documents  3. Copies of the certified copies of the priorical application from the International Bureau  * See the attached detailed Office action for a list of	have been received. have been received in Applic ty documents have been rece (PCT Rule 17.2(a)).	ation No ived in this National Stage
Attachmont(s)		3 "
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summa Paper No(s)/Mail 5) Notice of Informa 6) Other:	

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## **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claim 45-47, 50, 61-63, 65-67 and 70-72 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yoshioka et al (US 6149727) in view of Chu et al (US 6120660) and further in view of Shusaku Yanagawa (JP 10321545) as evidenced by Williams et al (US 5647953).

Yoshioka et al disclose a process chamber comprising a media delivery member (Fig 1-9), a spin chuck (Fig 1-20) and a plurality of point contact support structures (Fig 2 and Fig 3-27) and vacuum ring (Fig 2-24).

Yoshioka et al do not disclose a coating layer of silicon oxide on the spin chuck.

Chu et al disclose a susceptor coated by a silicon-bearing compound (Col 6 lines 48-60) like silicon dioxide (Col 12 claim 5). The thickness of the coating is disclosed to be 0.5-2.0 micron (Col 7 lines 18-19). Chu et al also teach that a silicon-bearing compound for protective layer is especially useful when a silicon substrate is used (Col 6 line 67).

Therefore it would have been obvious to one having ordinary skill in the art at the time invention was made to have a silicon based (silicon oxide) coating on the spin chuck including point contact structures to reduce micro-contamination, especially as silicon is generally the material of substrates for processing on the spin chuck and increase operating life of the chuck due to reduced abrasion.

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Yoshioka et al and Chu et al do not disclose a skirt around the periphery of the wafer support surface.

Shusaku Yanagawa discloses a skirt for thermal shielding around the periphery of the wafer support surface (Fig 1-6 and abstract), which does not support the substrate and is of a size that the total is greater than the size of substrate.

Therefore it would have been obvious to one having ordinary skill in the art at the time invention was made to have a skirt of thermal shield material so as to provide temperature uniformity on the substrate support surface.

Regarding claim 50, as the material of the coating is silicon oxide its hardness is generally less than the hardness of silicon. Moreover, as hardness of coating layer depends upon process conditions, it would be controllable within a range.

Regarding the citation of encapsulation of particulate matter, Williams et al disclose a method of coating interior surfaces of a chamber with dielectric layer of silicon dioxide after cleaning and disclose that this coating step traps particulates (Col 6 lines 5-10) and left over uncoated particles could contaminate substrates (Col 5 lines 23-28). This teaching clearly indicates that the surface property of this dielectric coated layer is such as to trap the contaminants and prevent their transfer to substrates.

Claims 51 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yoshioka et al (US 6149727) in view of Chu et al (US 6120660) and further in view of Shusaku Yanagawa (JP 10321545) as applied to claim 45 and further in view of Lu et al (US 5904778).

Yoshioka et al do not disclose the thickness of the silicon-bearing layer.

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Lu et al disclose a protective layer of silicon carbide less than 100 micron (Col 6 lines 21-

22) enough for protection. Too thick coatings could have a problem of peeling off.

Therefore it would have been obvious to one having ordinary skill in the art at the time

invention was made to make sure the thickness of the protective coating is enough for protection

as too thick layers may not be stable.

Response to Amendment

Applicant's arguments filed 3/25/2004 have been fully considered.

Applicant's argument regarding Chen is now moot in view of new grounds of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ram N Kackar whose telephone number is 571 272 1436. The

examiner can normally be reached on M-F 8:00 A.M to 5:P.M.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Gregory Mills can be reached on 571 272 1439. The fax phone number for the

organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is 703 308 0661.

SUPERVISORY PATENT EXAMINER

RK

**TECHNOLOGY CENTER 1700**